

+175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	Q _g Typ	I _D T _C = +25°C (Note 7)
40V	2.7mΩ @ V _{GS} = 10V	68.6nC	100A

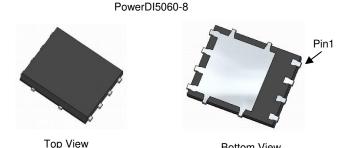
Description

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

Applications

- Engine management systems
- Body control electronics
- DC-DC converters

Site 1:



Site 2:

PowerDI5060-8/SWP (Type UX)



Top View



Bottom View

Bottom View

Features

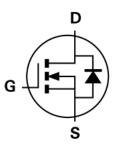
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low RDS(ON) Minimizes Power Losses
- Low Q_a Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

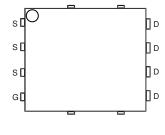
An automotive-compliant part is available under separate datasheet (DMTH4004SPSQ)

Mechanical Data

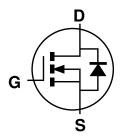
- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



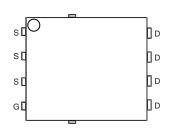
Internal Schematic



Top View Pin Configuration



Internal Schematic



Top View Pin Configuration

Ordering Information (Note 4)

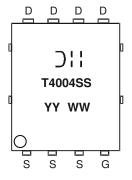
	Part Number	Dockers	Packing		
Part Number		Package	Qty.	Carrier	
	DMTH4004SPS-13	PowerDI5060-8	2500	Tape & Reel	
	DMTH4004SPS-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

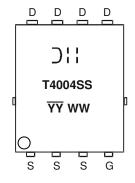
Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/



Marking Information





⊃¦¦ = Manufacturer's Marking T4004SS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage		V_{GSS}	±20	V
Continuous Drain Current (Note 5)	$T_A = +25$ °C $T_A = +70$ °C	ΙD	31 26	А
Continuous Drain Current (Note 6)	T _C = +25°C (Note 7) T _C = +100°C	lσ	100 100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ірм	350	Α	
Maximum Continuous Body Diode Forward Current (Note 5)	Is	100	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Isм	350	Α
Avalanche Current, L=0.2mH		las	45	Α
Avalanche Energy, L=0.2mH		Eas	200	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	3.6	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	41	°C/W
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		PD	167	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- Thermal resistance from junction to soldering point (on the exposed drain pad).
 Package limited.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

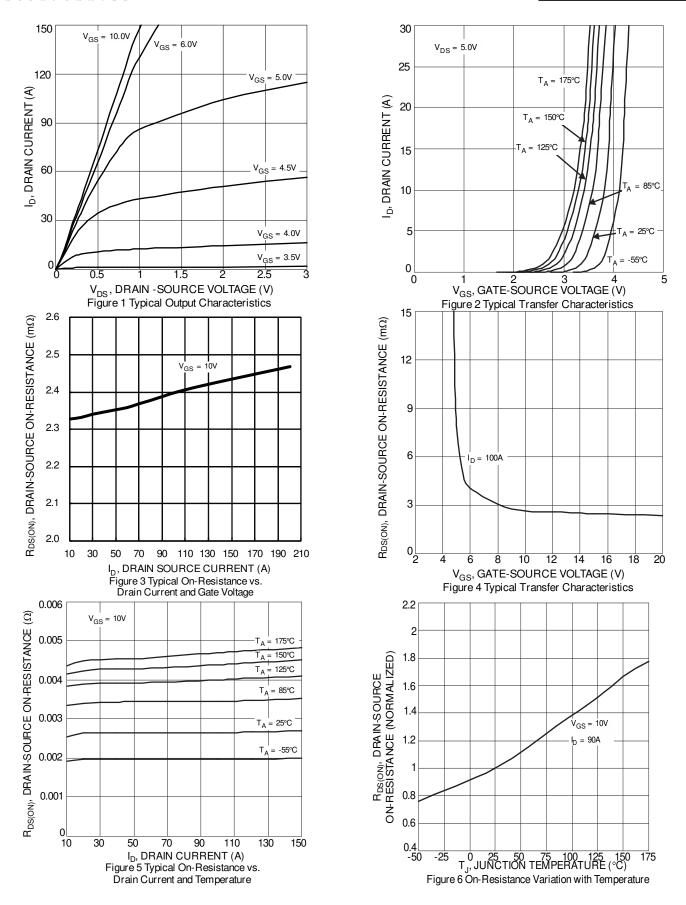
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BVDSS	40	_	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		_	1	μΑ	V _{DS} = 32V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	RDS(ON)	l	2.3	2.7	mΩ	VGS = 10V, ID = 90A	
Diode Forward Voltage	V _{SD}		0.9	1.2	V	V _G S = 0V, I _S = 20A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss		4,305	_	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss		1,441	_			
Reverse Transfer Capacitance	Crss	_	102	_			
Gate Resistance	Rg	_	0.77	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	68.6	_		V 00V I 00A	
Gate-Source Charge	Qgs	_	16.8	_	nC	$V_{DD} = 20V, I_D = 90A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q_{gd}	_	14.2	_			
Turn-On Delay Time	t _{D(ON)}	_	9.5	_			
Turn-On Rise Time	tR	_	6.7	_	ns	$V_{DD} = 20V, V_{GS} = 10V,$ $I_{D} = 90A, R_{G} = 3.5\Omega$	
Turn-Off Delay Time	t _{D(OFF)}	_	26.4	_			
Turn-Off Fall Time	tF	_	8.1	_			
Body Diode Reverse Recovery Time	trr	_	52.4	_	ns	I_ FOA di/dt 1000///-	
Body Diode Reverse Recovery Charge	Qrr	_	78.2	_	nC	I _F = 50A, di/dt = 100A/μs	

Notes:

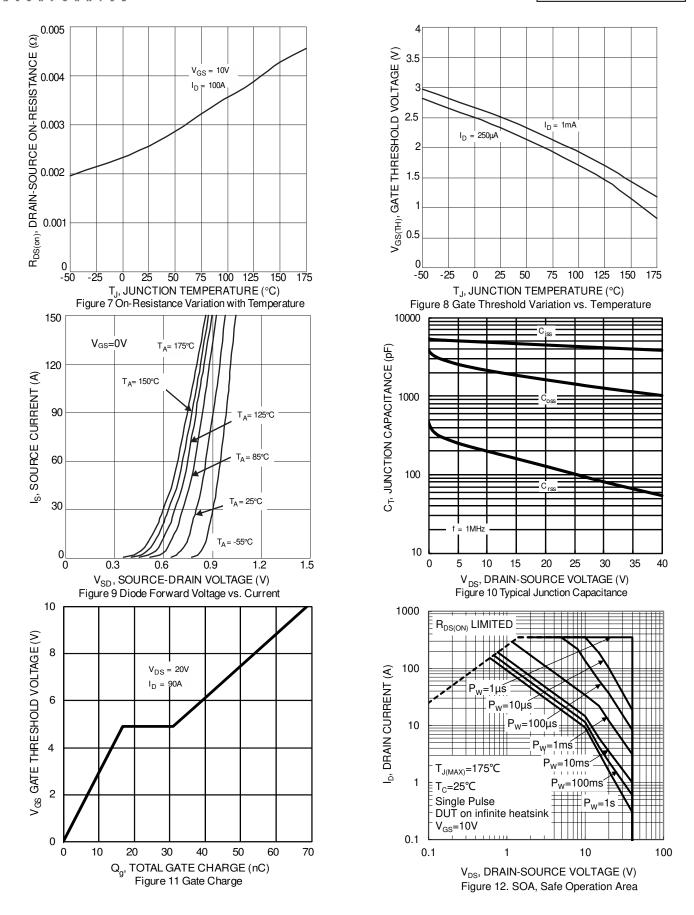
^{8.} Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to production testing.



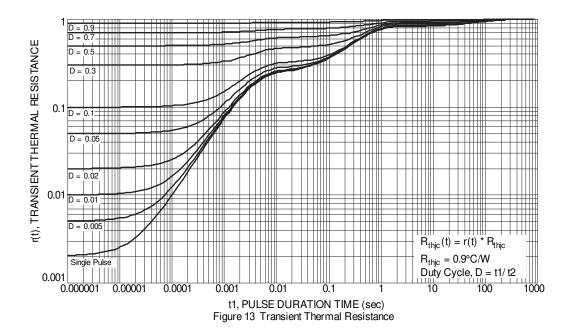










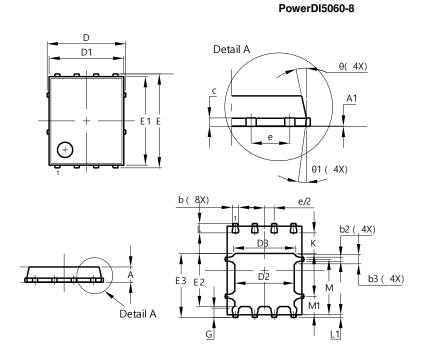




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

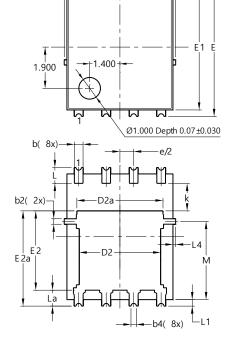
Site 1:



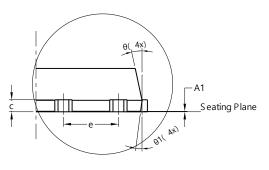
PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A 1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(3.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	•	1.27 BSC	,		
G	0.51	0.71	0.61		
Κ	0.51	-	-		
٦	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Site 2:

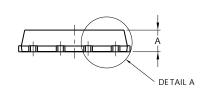
PowerDI5060-8/SWP (Type UX)



-D1



DETAIL A



PowerDI5060-8/SWP				
(Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	C).25REF	=	
С	0.230	0.330	0.277	
D		.15 BS0)	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78 4.18		3.98	
Е	6	.40 BS0		
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	.27BSC)	
k	1.05		-	
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0.050REF			
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

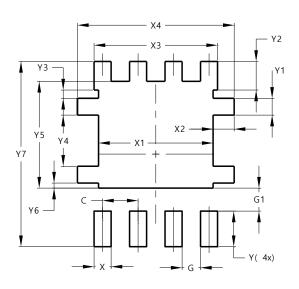


Suggested Pad Layout

 $Please\ see\ http://www.diodes.com/package-outlines.html\ for\ the\ latest\ version.$

Site 1:

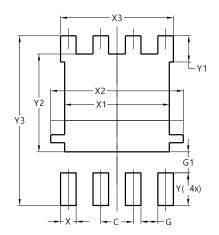
PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	0.755
Х3	4.420
X4	5.610
Υ	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y 7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
X	0.610
X1	4.100
X2	5.190
Х3	4.420
Υ	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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